# **MJ21294**

# **NPN Silicon Power Transistor**

With superior safe operating area performance, this power transistor is ideal for high temperature linear control circuits.

### **Features**

- Exceptional Safe Operating Area
- Dual Die Device with Standard 40 mil pins
- Pb-Free Package is Available\*

#### **Benefits**

- More Reliable Performance at Higher Powers
- Designed for Higher Temperature SOA
- Interchangeable with Standard Single Die TO-3 Devices

## **Applications**

- Linear Power Supplies
- Battery Conditioning
- DC Motor Control
- Positioners
- DC Heating Controls
- High Power Audio Amplifiers

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	$V_{CEO}$	250	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	400	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector–Emitter Voltage – 1.5 V	V <sub>CEX</sub>	400	Vdc
Collector Current – Continuous Peak (Note 1)	I <sub>C</sub>	20 40	Adc
Base Current – Continuous	I <sub>B</sub>	5.0	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate Above 25°C	P <sub>D</sub>	350 2.0	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 65 to +200	°C

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.50	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5  $\mu$ s, Duty Cycle  $\leq$ 10%. (continued)

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



# ON Semiconductor®

http://onsemi.com

20 AMPS 250 VOLTS 350 WATTS

> MARKING DIAGRAM



MEX

TO-204AA (TO-3) CASE 1-07



MJ21294 = Specific Device Code
G = Pb-Free Package
A = Assembly Site
YY = Year
WW = Work Week

# ORDERING INFORMATION

= Assembly Location

Device	Package	Shipping
MJ21294	TO-3	100 Units / Tray
MJ21294G	TO-3 (Pb-Free)	100 Units / Tray

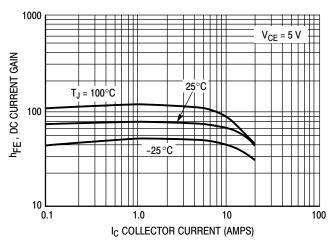
# MJ21294

# **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•			•
Collector-Emitter Sustaining Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0)	V <sub>CEO(sus)</sub>	250	-	-	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 200 Vdc, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	-	100	μAdc
Emitter Cutoff Current $(V_{CE} = 5 \text{ Vdc}, I_C = 0)$	I <sub>EBO</sub>	-	-	10	μAdc
Collector Cutoff Current (V <sub>CE</sub> = 250 Vdc, V <sub>BE(off)</sub> = 1.5 Vdc)	I <sub>CEX</sub>	-		100	μAdc
SECOND BREAKDOWN			-	-	
Second Breakdown Collector Current with Base Forward Biased (V <sub>CE</sub> = 40 Vdc, t = 1 s (non–repetitive)	I <sub>S/b</sub>	6.0	_	_	Adc
ON CHARACTERISTICS			-	-	
DC Current Gain $(I_C = 8 \text{ Adc}, V_{CE} = 5 \text{ Vdc})$ $(I_C = 16 \text{ Adc}, V_{CE} = 5 \text{ Vdc})$	h <sub>FE</sub>	40 15	_ _	100	
Base–Emitter On Voltage (I <sub>C</sub> = 8 Adc, V <sub>CE</sub> = 5 Vdc)	V <sub>BE(on)</sub>	-	-	1.4	Vdc
Collector–Emitter Saturation Voltage ( $I_C = 8$ Adc, $I_B = 0.8$ Adc) ( $I_C = 16$ Adc, $I_B = 3.2$ Adc)	V <sub>CE(sat)</sub>	- -	_ _	0.5 1.0	Vdc
DYNAMIC CHARACTERISTICS					
Current Gain Bandwidth Product $(I_C = 1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1 \text{ MHz})$	fT	4	_	_	MHz
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f_{test} = 1 \text{ MHz})$	C <sub>ob</sub>	-	-	500	pF

NOTE: Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤2%

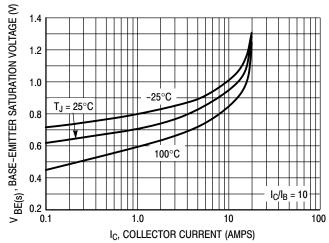
# **TYPICAL CHARACTERISTICS**



1.8 VBE(on), BASE-EMITTER VOLTAGE (VOLTS) 1.6 1.4 1.2 1.0 T<sub>J</sub> = 25°C 0.8 0.6 100°C 0.4 0.2 1.0 0.1 10 100 IC, COLLECTOR CURRENT (AMPS)

Figure 1. DC Current Gain

Figure 2. Base-Emitter Voltage



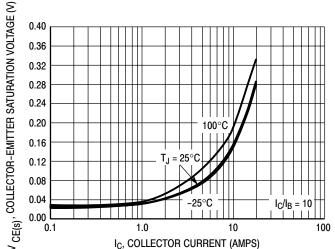


Figure 3. Base-Emitter Saturation Voltage

Figure 4. Collector-Emitter Saturation Voltage

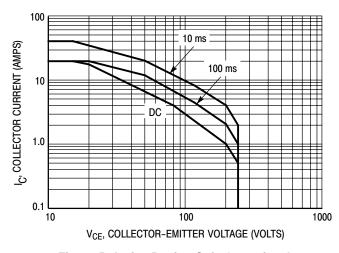


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

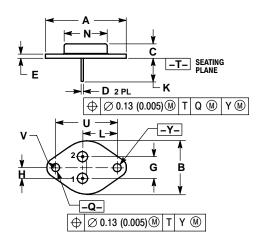
The data of Figure 5 is based on  $T_{J(pk)} = 200^{\circ}\text{C}$ ;  $T_{C}$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

# MJ21294

## PACKAGE DIMENSIONS

# TO-204AA (TO-3)

CASE 1-07 ISSUE Z



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	1.550	1.550 REF		REF	
В	-	1.050		26.67	
С	0.250	0.335	6.35	8.51	
D	0.038	0.043	0.97	1.09	
Е	0.055	0.070	1.40	1.77	
G	0.430	BSC	10.92 BSC		
Н	0.215	0.215 BSC		BSC	
K	0.440	0.480	11.18 12.1		
L	0.665	BSC	16.89	BSC	
N	-	0.830		21.08	
Q	0.151	0.165	3.84	4.19	
U	1.187	1.187 BSC		30.15 BSC	
V	0 131	0 188	3 33	Δ 77	

PIN 1. BASE 2. EMITTER CASE: COLLECTOR

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

# **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.